

**8-OUTPUT VERY LOW POWER PCIE GEN 1-2-3 CLOCK GENERATOR**
**9FGV0841**
**Description**

The 9FGV0841 is an 8-output very low power clock generator for PCIe Gen1-2-3 applications with integrated output terminations providing  $Z_o=100\Omega$ . The device has 8 output enables for clock management and supports 2 different spread spectrum levels in addition to spread off.

**Recommended Application**

PCIe Gen1-2-3 Clock Generator

**Output Features**

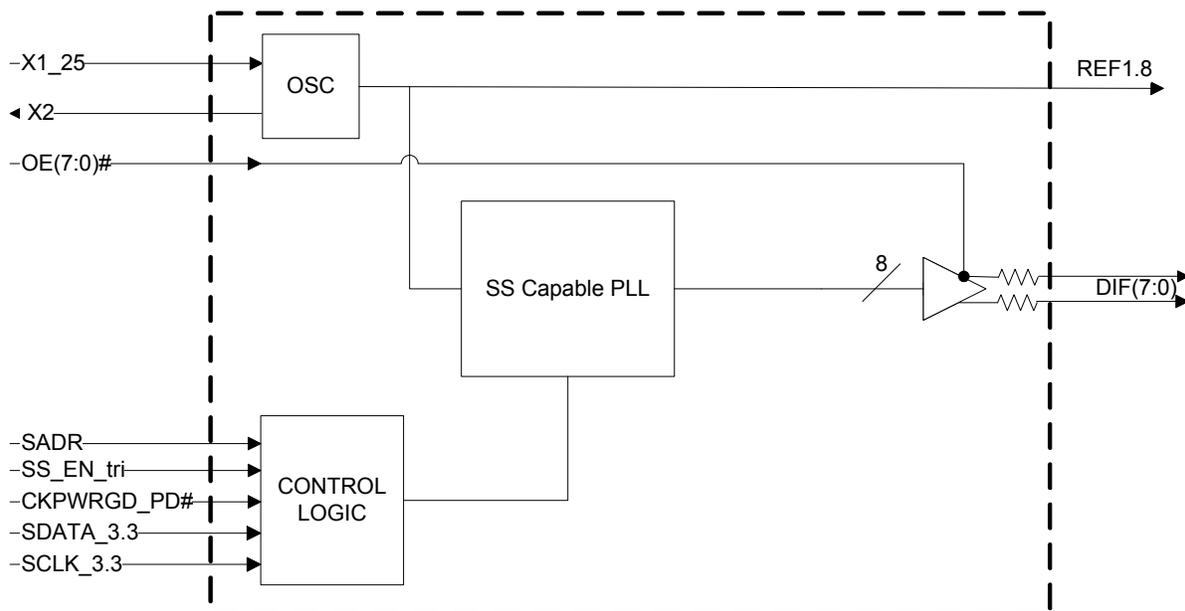
- 8 - 0.7V low-power HCSL-compatible (LP-HCSL) DIF pairs w/ $Z_o=100\Omega$
- 1 - 1.8V LVCMOS REF output w/Wake-On-LAN (WOL) support

**Key Specifications**

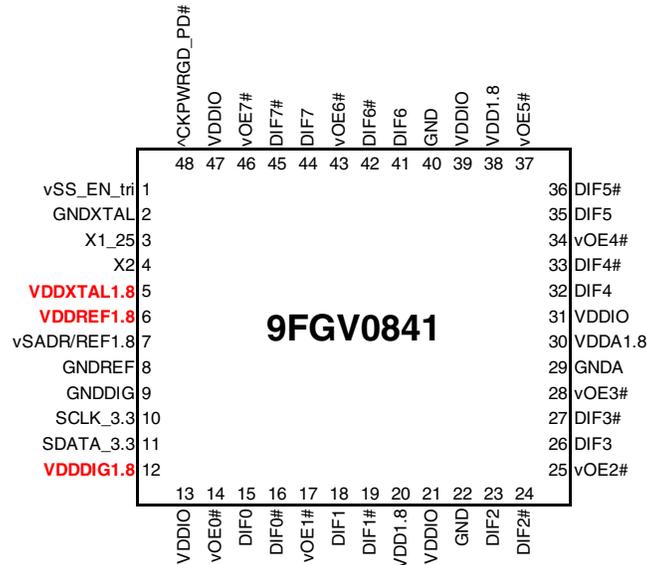
- DIF cycle-to-cycle jitter <50ps
- DIF output-to-output skew <50ps
- DIF phase jitter is PCIe Gen1-2-3 compliant
- REF phase jitter is < 1.5ps RMS

**Features/Benefits**

- Integrated terminations provide  $100\Omega$  differential  $Z_o$ ; reduced component count and board space
- 1.8V operation; reduced power consumption
- Outputs can optionally be supplied from any voltage between 1.05 and 1.8V; maximum power savings
- OE# pins; support DIF power management
- LP-HCSL differential clock outputs; reduced power and board space
- Programmable Slew rate for each output; allows tuning for various line lengths
- Programmable output amplitude; allows tuning for various application environments
- DIF outputs blocked until PLL is locked; clean system start-up
- Selectable 0%, -0.25% or -0.5% spread on DIF outputs; reduces EMI
- External 25MHz crystal; supports tight ppm with 0 ppm synthesis error
- Configuration can be accomplished with strapping pins; SMBus interface not required for device control
- 3.3V tolerant SMBus interface works with legacy controllers
- Space saving 48-pin 6x6 mm MLF; minimal board space
- Selectable SMBus addresses; multiple devices can easily share an SMBus segment

**Block Diagram**


## Pin Configuration



**48-pin MLF, 6x6 mm, 0.4mm pitch**

- vv prefix indicates internal 60KOhm pull down resistor
- v prefix indicates internal 120KOhm pull down resistor
- ^ prefix indicates internal 120KOhm pull up resistor

**Pins 5, 6 and 12 are the Suspend voltage rails.**

## SMBus Address Selection Table

	SADR	Address	+ Read/Write Bit
State of SADR on first application of CKPWRGD_PD#	0	1101000	x
	1	1101010	x

## Power Management Table

CKPWRGD_PD#	SMBus OE bit	DIFx			REF
		OEx#	True O/P	Comp. O/P	
0	X	X	Low	Low	Hi-Z <sup>1</sup>
1	1	0	Running	Running	Running
1	0	1	Low	Low	Low

1. REF is Hi-Z until the 1st assertion of CKPWRGD\_PD# high. After this, when CKPWRGD\_PD# is low, REF is Low.

## Power Connections

Pin Number			Description
VDD	VDDIO	GND	
5		2	XTAL OSC
6		8	REF Power
12		9	Digital (dirty) Power
20,38	13,21,31,39,47	22,29,40	DIF outputs
30		29	PLL Analog

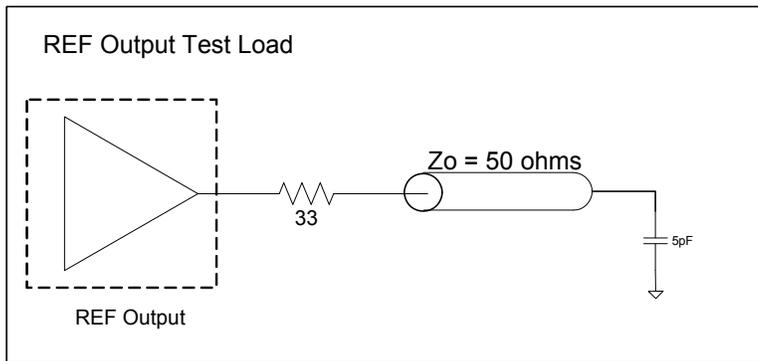
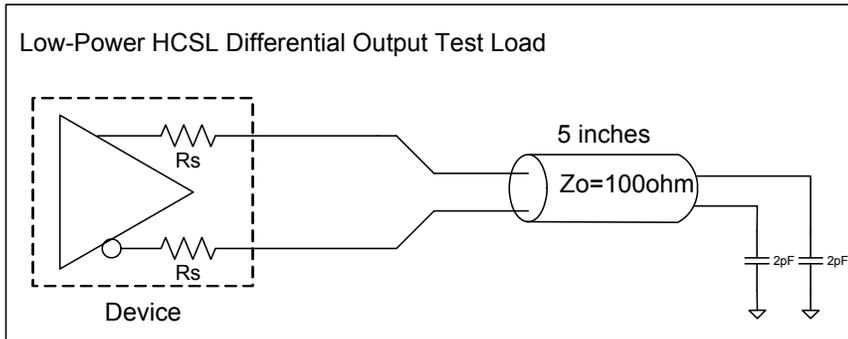
## Pin Descriptions

PIN #	PIN NAME	TYPE	DESCRIPTION
1	vSS_EN_tri	LATCHED IN	Latched select input to select spread spectrum amount at initial power up : 1 = -0.5% spread, M = -0.25%, 0 = Spread Off
2	GNDXTAL	GND	GND for XTAL
3	X1_25	IN	Crystal input, Nominally 25.00MHz.
4	X2	OUT	Crystal output.
5	VDDXTAL1.8	PWR	Power supply for XTAL, nominal 1.8V
6	VDDREF1.8	PWR	VDD for REF output. nominal 1.8V.
7	vSADR/REF1.8	LATCHED I/O	Latch to select SMBus Address/1.8V LVCMOS copy of X1 pin.
8	GNDREF	GND	Ground pin for the REF outputs.
9	GNDDIG	GND	Ground pin for digital circuitry
10	SCLK_3.3	IN	Clock pin of SMBus circuitry, 3.3V tolerant.
11	SDATA_3.3	I/O	Data pin for SMBus circuitry, 3.3V tolerant.
12	VDDDIG1.8	PWR	1.8V digital power (dirty power)
13	VDDIO	PWR	Power supply for differential outputs
14	vOE0#	IN	Active low input for enabling DIF pair 0. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
15	DIF0	OUT	Differential true clock output
16	DIF0#	OUT	Differential Complementary clock output
17	vOE1#	IN	Active low input for enabling DIF pair 1. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
18	DIF1	OUT	Differential true clock output
19	DIF1#	OUT	Differential Complementary clock output
20	VDD1.8	PWR	Power supply, nominal 1.8V
21	VDDIO	PWR	Power supply for differential outputs
22	GND	GND	Ground pin.
23	DIF2	OUT	Differential true clock output
24	DIF2#	OUT	Differential Complementary clock output
25	vOE2#	IN	Active low input for enabling DIF pair 2. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
26	DIF3	OUT	Differential true clock output
27	DIF3#	OUT	Differential Complementary clock output
28	vOE3#	IN	Active low input for enabling DIF pair 3. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
29	GNDA	GND	Ground pin for the PLL core.
30	VDDA1.8	PWR	1.8V power for the PLL core.
31	VDDIO	PWR	Power supply for differential outputs
32	DIF4	OUT	Differential true clock output
33	DIF4#	OUT	Differential Complementary clock output
34	vOE4#	IN	Active low input for enabling DIF pair 4. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
35	DIF5	OUT	Differential true clock output
36	DIF5#	OUT	Differential Complementary clock output
37	vOE5#	IN	Active low input for enabling DIF pair 5. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
38	VDD1.8	PWR	Power supply, nominal 1.8V
39	VDDIO	PWR	Power supply for differential outputs

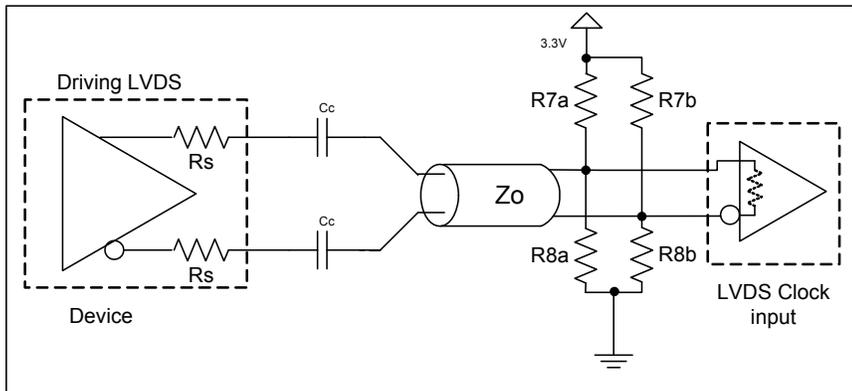
**Pin Descriptions (cont.)**

PIN #	PIN NAME	TYPE	DESCRIPTION
40	GND	GND	Ground pin.
41	DIF6	OUT	Differential true clock output
42	DIF6#	OUT	Differential Complementary clock output
43	vOE6#	IN	Active low input for enabling DIF pair 6. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
44	DIF7	OUT	Differential true clock output
45	DIF7#	OUT	Differential Complementary clock output
46	vOE7#	IN	Active low input for enabling DIF pair 7. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
47	VDDIO	PWR	Power supply for differential outputs
48	^CKPWRGD_PD#	IN	Input notifies device to sample latched inputs and start up on first high assertion. Low enters Power Down Mode, subsequent high assertions exit Power Down Mode. This pin has internal pull-up resistor.

### Test Loads



### Alternate Terminations



#### Driving LVDS inputs with the 9FGV0841

Component	Value		Note
	Receiver has termination	Receiver does not have termination	
R7a, R7b	10K ohm	140 ohm	
R8a, R8b	5.6K ohm	75 ohm	
Cc	0.1 uF	0.1 uF	
Vcm	1.2 volts	1.2 volts	

## Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9FGV0841. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
1.8V Supply Voltage	VDDXX	Applies to VDD, VDDA and VDDIO	-0.5		2.5	V	1,2
Input Voltage	V <sub>IN</sub>		-0.5		V <sub>DD</sub> +0.5V	V	1, 3
Input High Voltage, SMBus	V <sub>IHSMB</sub>	SMBus clock and data pins			3.6V	V	1
Storage Temperature	T <sub>s</sub>		-65		150	°C	1
Junction Temperature	T <sub>j</sub>				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup>Operation under these conditions is neither implied nor guaranteed.

<sup>3</sup>Not to exceed 2.5V.

## Electrical Characteristics—Current Consumption

TA = T<sub>COM</sub> or T<sub>IND</sub>; Supply Voltage per VDD, VDDIO of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	I <sub>DDAOP</sub>	VDDA, All outputs active @100MHz		6	8	mA	1
	I <sub>DDOP</sub>	VDD, All outputs active @100MHz		12	15	mA	1
	I <sub>DDIOOP</sub>	VDDIO, All outputs active @100MHz		28	35	mA	1
Suspend Supply Current	I <sub>DDSUSP</sub>	Pins 5, 6, and 12, PD#=0, Wake-On-LAN enabled		6	8	mA	1, 2
Powerdown Current	I <sub>DDPD</sub>	VDDA, VDD, Outputs Low/Low		0.6	1	mA	1, 3
	I <sub>DDIODZ</sub>	VDDIO, Outputs Low/Low		0	0.5	mA	1, 3

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup>This is the current required to have the REF output running in suspend mode (Byte 3, bit 5 = 1)

<sup>3</sup>PD# = 0 and Byte 3, bit 5 = 0.

## Electrical Characteristics—Differential Output Duty Cycle, Jitter, and Skew Characteristics

TA = T<sub>COM</sub> or T<sub>IND</sub>; Supply Voltage per VDD, VDDIO of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Duty Cycle	t <sub>DC</sub>	Measured differentially, PLL Mode	45	49.9	55	%	1
Skew, Output to Output	t <sub>sk3</sub>	V <sub>T</sub> = 50%		37	50	ps	1
Jitter, Cycle to cycle	t <sub>JCYC-CYC</sub>	PLL mode		12	50	ps	1,2

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup>Measured from differential waveform

## Electrical Characteristics–Input/Supply/Common Parameters–Normal Operating Conditions

TA = T<sub>COM</sub> or T<sub>IND</sub>; Supply Voltage per VDD, VDDIO of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
1.8V Supply Voltage	VDD	Supply voltage for core, analog and single-ended LVCMOS outputs	1.7	1.8	1.9	V	1
IO Supply Voltage	VDDIO	Supply voltage for differential Low Power Outputs	0.9975	1.05	1.9	V	1
Ambient Operating Temperature	T <sub>COM</sub>	Commercial range	0	25	70	°C	1
	T <sub>IND</sub>	Industrial range	-40	25	85	°C	1
Input High Voltage	V <sub>IH</sub>	Single-ended inputs, except SMBus	0.75 V <sub>DD</sub>		V <sub>DD</sub> + 0.3	V	1
Input Mid Voltage	V <sub>IM</sub>	Single-ended tri-level inputs ('_tri' suffix)	0.4 V <sub>DD</sub>		0.6 V <sub>DD</sub>	V	1
Input Low Voltage	V <sub>IL</sub>	Single-ended inputs, except SMBus	-0.3		0.25 V <sub>DD</sub>	V	1
Schmitt Trigger Positive Going Threshold Voltage	V <sub>T+</sub>	Single-ended inputs, where indicated	0.4 V <sub>DD</sub>		0.7 V <sub>DD</sub>	V	1
Schmitt Trigger Negative Going Threshold Voltage	V <sub>T-</sub>	Single-ended inputs, where indicated	0.1 V <sub>DD</sub>		0.4 V <sub>DD</sub>	V	1
Hysteresis Voltage	V <sub>H</sub>	V <sub>T+</sub> - V <sub>T-</sub>	0.1 V <sub>DD</sub>		0.4 V <sub>DD</sub>	V	1
Output High Voltage	V <sub>IH</sub>	Single-ended outputs, except SMBus. I <sub>OH</sub> = -2mA	V <sub>DD</sub> -0.45			V	1
Output Low Voltage	V <sub>IL</sub>	Single-ended outputs, except SMBus. I <sub>OL</sub> = -2mA			0.45	V	1
Input Current	I <sub>IN</sub>	Single-ended inputs, V <sub>IN</sub> = GND, V <sub>IN</sub> = VDD	-5		5	uA	1
	I <sub>INP</sub>	Single-ended inputs V <sub>IN</sub> = 0 V; Inputs with internal pull-up resistors V <sub>IN</sub> = VDD; Inputs with internal pull-down resistors	-200		200	uA	1
Input Frequency	F <sub>in</sub>	XTAL <sub>1</sub> , or X1 input	23	25	27	MHz	1
Pin Inductance	L <sub>pin</sub>				7	nH	1
Capacitance	C <sub>IN</sub>	Logic Inputs, except DIF_IN	1.5		5	pF	1
	C <sub>OUT</sub>	Output pin capacitance			6	pF	1
Clk Stabilization	T <sub>STAB</sub>	From V <sub>DD</sub> Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock		0.6	1.8	ms	1,2
SS Modulation Frequency	f <sub>MOD</sub>	Allowable Frequency (Triangular Modulation)	31	31.6	32	kHz	1
OE# Latency	t <sub>LATOE#</sub>	DIF start after OE# assertion DIF stop after OE# deassertion	1	2	3	clocks	1,3
Tdrive_PD#	t <sub>DRVPD</sub>	DIF output enable after PD# de-assertion			300	us	1,3
Tfall	t <sub>F</sub>	Fall time of single-ended control inputs			5	ns	1,2
Trise	t <sub>R</sub>	Rise time of single-ended control inputs			5	ns	1,2
SMBus Input Low Voltage	V <sub>ILSMB</sub>	V <sub>DDSMB</sub> = 3.3V, see note 4 for V <sub>DDSMB</sub> < 3.3V			0.8	V	1,4
SMBus Input High Voltage	V <sub>IHSMB</sub>	V <sub>DDSMB</sub> = 3.3V, see note 5 for V <sub>DDSMB</sub> < 3.3V	2.1		3.6	V	1,5
SMBus Output Low Voltage	V <sub>OLSMB</sub>	@ I <sub>PULLUP</sub>			0.4	V	1
SMBus Sink Current	I <sub>PULLUP</sub>	@ V <sub>OL</sub>	4			mA	1
Nominal Bus Voltage	V <sub>DDSMB</sub>		1.7		3.6	V	1
SCLK/SDATA Rise Time	t <sub>RSMB</sub>	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t <sub>FSMB</sub>	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f <sub>MAXSMB</sub>	Maximum SMBus operating frequency			400	kHz	1

<sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Control input must be monotonic from 20% to 80% of input swing.

<sup>3</sup> Time from deassertion until outputs are >200 mV

<sup>4</sup> For V<sub>DDSMB</sub> < 3.3V, V<sub>ILSMB</sub> <= 0.35V<sub>DDSMB</sub>

<sup>5</sup> For V<sub>DDSMB</sub> < 3.3V, V<sub>IHSMB</sub> >= 0.65V<sub>DDSMB</sub>

## Electrical Characteristics–DIF 0.7V Low Power HCSL Outputs

TA = T<sub>COM</sub> or T<sub>IND</sub>; Supply Voltage per VDD, VDDIO of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	Trf	Scope averaging on 3.0V/ns setting	2	2.7	4	V/ns	1, 2, 3
		Scope averaging on 2.0V/ns setting	1	2	3	V/ns	1, 2, 3
Slew rate matching	ΔTrf	Slew rate matching, Scope averaging on		6.5	20	%	1, 2, 4
Voltage High	V <sub>HIGH</sub>	Statistical measurement on single-ended signal using oscilloscope math function. (Scope averaging on)	660	784	850	mV	1,7,8
Voltage Low	V <sub>LOW</sub>		-150	-33	150		1
Max Voltage	V <sub>max</sub>	Measurement on single ended signal using absolute value. (Scope averaging off)		816	1150	mV	1
Min Voltage	V <sub>min</sub>		-300	-42			1
Vswing	Vswing	Scope averaging off	300	1634		mV	1, 2
Crossing Voltage (abs)	V <sub>cross_abs</sub>	Scope averaging off	250	427	550	mV	1, 5
Crossing Voltage (var)	ΔV <sub>cross</sub>	Scope averaging off		12	140	mV	1, 6

<sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Measured from differential waveform

<sup>3</sup> Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

<sup>4</sup> Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

<sup>5</sup> V<sub>cross</sub> is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

<sup>6</sup> The total variation of all V<sub>cross</sub> measurements in any particular system. Note that this is a subset of V<sub>cross\_min/max</sub> (V<sub>cross</sub> absolute) allowed. The intent is to limit V<sub>cross</sub> induced modulation by setting ΔV<sub>cross</sub> to be smaller than V<sub>cross</sub> absolute.

<sup>7</sup> 660mV V<sub>high</sub> is the minimum when VDDIO is >= 1.05V +/-5%. If VDDIO is < 1.05V +/-5%, the minimum V<sub>high</sub> will be VDDIO<sub>min</sub> - 250mV. For example for VDDIO = 0.9V +/-5%, V<sub>HIGHmin</sub> will be 860mV - 250mV = 610mV.

<sup>8</sup> At default SMBus settings.

## Electrical Characteristics–Differential Output Phase Jitter Parameters

TA = T<sub>COM</sub> or T<sub>IND</sub>; Supply Voltage per VDD, VDDIO of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	INDUSTRY LIMIT	UNITS	NOTES
Phase Jitter, PCI Express	t <sub>jphPCIeG1</sub>	PCIe Gen 1	20	25	32	86	ps (p-p)	1,2,3,5
	t <sub>jphPCIeG2</sub>	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz	0.8	0.9	1	3	ps (rms)	1,2,5
		PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)	1.5	1.6	1.8	3.1	ps (rms)	1,2,5
	t <sub>jphPCIeG3</sub>	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)	0.34	0.36	0.43	1	ps (rms)	1,2,4,5

<sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> See <http://www.pcisig.com> for complete specs

<sup>3</sup> Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

<sup>4</sup> Calculated from Intel-supplied Clock Jitter Tool

<sup>5</sup> Applies to all differential outputs

## Electrical Characteristics–REF

TA = T<sub>COM</sub> or T<sub>IND</sub>; Supply Voltage per VDD of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	Notes
Long Accuracy	ppm	see T <sub>period</sub> min-max values	0			ppm	1,2
Clock period	T <sub>period</sub>	25 MHz output nominal		40		ns	1,2
Rise/Fall Slew Rate	t <sub>ff1</sub>	V <sub>OH</sub> = VDD-0.45V, V <sub>OL</sub> = 0.45V	0.5	1.3	2.5	V/ns	1,3
Duty Cycle	d <sub>t1X</sub>	V <sub>T</sub> = VDD/2 V	45	49.1	55	%	1,4
Duty Cycle Distortion	d <sub>tcd</sub>	V <sub>T</sub> = VDD/2 V	0	2	3	%	1,5
Jitter, cycle to cycle	t <sub>jcyc-cyc</sub>	V <sub>T</sub> = VDD/2 V		19	250	ps	1,4
Noise floor	t <sub>jdBc1k</sub>	1kHz offset		-130	-105	dBc	1,4
Noise floor	t <sub>jdBc10k</sub>	10kHz offset to Nyquist		-140	-120	dBc	1,4
Jitter, phase	t <sub>iphREF</sub>	12kHz to 5MHz		0.63	1.5	ps (rms)	1,4

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup>All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REF is trimmed to 25.00 MHz

<sup>3</sup>Typical value occurs when REF slew rate is set to default value

<sup>4</sup>When driven by a crystal.

<sup>5</sup>When driven by an external oscillator via the X1 pin. X2 should be floating in this case.

## Clock Periods–Differential Outputs with Spread Spectrum Disabled

SSC OFF	Center Freq. MHz	Measurement Window							Units	Notes
		1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
		-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max		
DIF	100.00	9.94900		9.99900	10.00000	10.00100		10.05100	ns	1,2

## Clock Periods–Differential Outputs with Spread Spectrum Enabled

SSC ON	Center Freq. MHz	Measurement Window							Units	Notes
		1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
		-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max		
DIF	99.75	9.94906	9.99906	10.02406	10.02506	10.02607		10.05107	ns	1,2

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup>All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REF is trimmed to 25.00 MHz

## General SMBus Serial Interface Information

### How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will **acknowledge**
- Controller (host) sends the beginning byte location = N
- IDT clock will **acknowledge**
- Controller (host) sends the byte count = X
- IDT clock will **acknowledge**
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will **acknowledge** each byte **one at a time**
- Controller (host) sends a Stop bit

Index Block Write Operation		
Controller (Host)		IDT (Slave/Receiver)
T	starT bit	
Slave Address		
WR	WRite	
Beginning Byte = N		ACK
		ACK
Data Byte Count = X		ACK
Beginning Byte N		ACK
O	X Byte	O
O		O
O		O
Byte N + X - 1		ACK
P	stoP bit	

**Note:** Read/Write address is latched on SADR pin.

### How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will **acknowledge**
- Controller (host) sends the beginning byte location = N
- IDT clock will **acknowledge**
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- IDT clock will **acknowledge**
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends **Byte 0 through Byte X (if X<sub>(H)</sub> was written to Byte 8)**
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

Index Block Read Operation		
Controller (Host)		IDT (Slave/Receiver)
T	starT bit	
Slave Address		
WR	WRite	
Beginning Byte = N		ACK
		ACK
RT	Repeat starT	
Slave Address		
RD	ReaD	
		ACK
ACK		Data Byte Count=X
		Beginning Byte N
ACK		O
O		O
O		O
O		
		Byte N + X - 1
N	Not acknowledge	
P	stoP bit	

SMBus Table: Output Enable Register <sup>1</sup>

Byte 0	Name	Control Function	Type	0	1	Default
Bit 7	DIF OE7	Output Enable	RW	Low/Low	Enabled	1
Bit 6	DIF OE6	Output Enable	RW	Low/Low	Enabled	1
Bit 5	DIF OE5	Output Enable	RW	Low/Low	Enabled	1
Bit 4	DIF OE4	Output Enable	RW	Low/Low	Enabled	1
Bit 3	DIF OE3	Output Enable	RW	Low/Low	Enabled	1
Bit 2	DIF OE2	Output Enable	RW	Low/Low	Enabled	1
Bit 1	DIF OE1	Output Enable	RW	Low/Low	Enabled	1
Bit 0	DIF OE0	Output Enable	RW	Low/Low	Enabled	1

1. A low on these bits will override the OE# pin and force the differential output Low/Low

SMBus Table: SS Readback and Control Register

Byte 1	Name	Control Function	Type	0	1	Default
Bit 7	SSENRB1	SS Enable Readback Bit1	R	00' for SS_EN_tri = 0, '01' for SS_EN_tri = 'M', '11 for SS_EN_tri = '1'		Latch
Bit 6	SSENRB1	SS Enable Readback Bit0	R			Latch
Bit 5	SSEN_SWCNTRL	Enable SW control of SS	RW	Values in B1[7:6] control SS amount	Values in B1[4:3] control SS amount.	0
Bit 4	SSENSW1	SS Enable Software Ctl Bit1	RW <sup>1</sup>	00' = SS Off, '01' = -0.25% SS,		0
Bit 3	SSENSW0	SS Enable Software Ctl Bit0	RW <sup>1</sup>	'10' = Reserved, '11' = -0.5% SS		0
Bit 2	Reserved					1
Bit 1	AMPLITUDE 1	Controls Output Amplitude	RW	00 = 0.6V	01 = 0.7V	1
Bit 0	AMPLITUDE 0		RW	10 = 0.8V	11 = 0.9V	0

1. B1[5] must be set to a 1 for these bits to have any effect on the part.

SMBus Table: DIF Slew Rate Control Register

Byte 2	Name	Control Function	Type	0	1	Default
Bit 7	SLEWRATESEL DIF7	Adjust Slew Rate of DIF7	RW	2.0V/ns	3.0V/ns	1
Bit 6	SLEWRATESEL DIF6	Adjust Slew Rate of DIF6	RW	2.0V/ns	3.0V/ns	1
Bit 5	SLEWRATESEL DIF5	Adjust Slew Rate of DIF5	RW	2.0V/ns	3.0V/ns	1
Bit 4	SLEWRATESEL DIF4	Adjust Slew Rate of DIF4	RW	2.0V/ns	3.0V/ns	1
Bit 3	SLEWRATESEL DIF3	Adjust Slew Rate of DIF3	RW	2.0V/ns	3.0V/ns	1
Bit 2	SLEWRATESEL DIF2	Adjust Slew Rate of DIF2	RW	2.0V/ns	3.0V/ns	1
Bit 1	SLEWRATESEL DIF1	Adjust Slew Rate of DIF1	RW	2.0V/ns	3.0V/ns	1
Bit 0	SLEWRATESEL DIF0	Adjust Slew Rate of DIF0	RW	2.0V/ns	3.0V/ns	1

SMBus Table: Nominal Vhigh Amplitude Control/ REF Control Register

Byte 3	Name	Control Function	Type	0	1	Default
Bit 7	REF	Slew Rate Control	RW	00 = 0.9V/ns	01 = 1.3V/ns	0
Bit 6			RW	10 = 1.6V/ns	11 = 1.8V/ns	1
Bit 5	REF Power Down Function	Wake-on-Lan Enable for REF	RW	REF does not run in Power Down	REF runs in Power Down	0
Bit 4	REF OE	REF Output Enable	RW	Low	Enabled	1
Bit 3	Reserved					1
Bit 2	Reserved					1
Bit 1	Reserved					1
Bit 0	Reserved					1

Byte 4 is Reserved

SMBus Table: Revision and Vendor ID Register

Byte 5	Name	Control Function	Type	0	1	Default
Bit 7	RID3	Revision ID	R	A rev = 0000		0
Bit 6	RID2		R			0
Bit 5	RID1		R			0
Bit 4	RID0		R			0
Bit 3	VID3	VENDOR ID	R	0001 = IDT		0
Bit 2	VID2		R			0
Bit 1	VID1		R			0
Bit 0	VID0		R			1

SMBus Table: Device Type/Device ID

Byte 6	Name	Control Function	Type	0	1	Default
Bit 7	Device Type1	Device Type	R	00 = FGV, 01 = DBV, 10 = DMV, 11= Reserved		0
Bit 6	Device Type0		R			0
Bit 5	Device ID5	Device ID	R	001000 binary or 08 hex		0
Bit 4	Device ID4		R			0
Bit 3	Device ID3		R			1
Bit 2	Device ID2		R			0
Bit 1	Device ID1		R			0
Bit 0	Device ID0		R			0

SMBus Table: Byte Count Register

Byte 7	Name	Control Function	Type	0	1	Default
Bit 7		Reserved				0
Bit 6		Reserved				0
Bit 5		Reserved				0
Bit 4	BC4	Byte Count Programming	RW	Writing to this register will configure how many bytes will be read back, default is = 8 bytes.		0
Bit 3	BC3		RW			1
Bit 2	BC2		RW			0
Bit 1	BC1		RW			0
Bit 0	BC0		RW			0

## Recommended Crystal Characteristics (3225 package)

PARAMETER	VALUE	UNITS	NOTES
Frequency	25	MHz	1
Resonance Mode	Fundamental	-	1
Frequency Tolerance @ 25°C	±20	PPM Max	1
Frequency Stability, ref @ 25°C Over Operating Temperature Range	±20	PPM Max	1
Temperature Range (commercial)	0~70	°C	1
Temperature Range (industrial)	-40~85	°C	2
Equivalent Series Resistance (ESR)	50	Ω Max	1
Shunt Capacitance (C <sub>0</sub> )	7	pF Max	1
Load Capacitance (C <sub>L</sub> )	8	pF Max	1
Drive Level	0.3	mW Max	1
Aging per year	±5	PPM Max	1

### Notes:

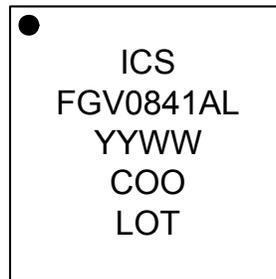
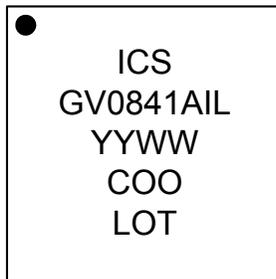
1. Fox Electronics 603-25-150 or equivalent
2. For I-temp, contact Fox Electronics at Foxonline.com

## Thermal Characteristics

PARAMETER	SYMBOL	CONDITIONS	PKG	TYP.	UNITS	NOTES
Thermal Resistance	$\theta_{JC}$	Junction to Case	NDG48	33	°C/W	1
	$\theta_{Jb}$	Junction to Base		2.1	°C/W	1
	$\theta_{JA0}$	Junction to Air, still air		37	°C/W	1
	$\theta_{JA1}$	Junction to Air, 1 m/s air flow		30	°C/W	1
	$\theta_{JA3}$	Junction to Air, 3 m/s air flow		27	°C/W	1
	$\theta_{JA5}$	Junction to Air, 5 m/s air flow		26	°C/W	1

<sup>1</sup>ePad soldered to board

## Marking Diagrams



### Notes:

1. Line 2 is the truncated part number.
2. 'L' denotes RoHS compliant package.
3. 'I' denotes industrial temperature grade.
4. 'YYWW' is the last two digits of the year and week that the part was assembled.
5. 'COO' denotes country of origin.
6. 'LOT' is the lot number.



## Revision History

Rev.	Issue Date	Intiator	Description	Page #
A	8/14/2012	RDW	1. Changed Description, Recommended Application and DS title to say "Clock Generator" instead of "Frequency Generator" 2. Changed Output Features text. 3. Changed block diagram to highlight integrated terminations. 4. Updated electrical tables with char data, removed "Clock Periods-Single-ended Outputs" table which was redundant. 5. Changed integration range for phase jitter calculation of REF from "12kHz to 20MHz" to "12kHz to 5MHz" 6. Corrected Byte 6 7. Added Thermal Data and Recommended Crystal tables 8. Corrected Part Marking Diagram 9. Added NDG-48 package code to package diagram 10. Move to final	1,6-9,12,13,14
B	10/3/2012	RDW	Pin description for pin named "VDDREF1.8" is unclear due to typographical error. The pin description for pin with this name is currently, VDD for REF output. 1.8V nominal 3.3V. The correct description should be "VDD for REF output. nominal 1.8V."	3
C	1/7/2013	AT	1. Added SADR column to SMBus Address Selection table. 2. Changed VIH min. from $0.65 \cdot VDD$ to $0.75 \cdot VDD$ , VIM min. from $0.35 \cdot VDD$ to $0.4 \cdot VDD$ and max. from $0.65 \cdot VDD$ to $0.6 \cdot VDD$ , and VIL max. from $0.35 \cdot VDD$ to $0.25 \cdot VDD$	Various
D	2/4/2013	RDW	1. Corrected XTAL OSC GND from pin 1 to pin 2 in the Power Connections Table.	2

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